Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
0.175 inches
Overall Height:
0.073 inches
Overall Width:
0.073 inches
Function For Which Designed:
Switching
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, dc and 75.0 working peak reverse voltage
Current Rating Per Characteristic:
200.00 milliamperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Precious Material And Location:
Terminals silver
Precious Material:
Silver
Terminal Type And Quantity:
2 ferrule
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0